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FGA30S120P 1300 V, 30 A Shorted-anode IGBT

Features

- High Speed Switching
- Low Saturation Voltage: V_{CE(sat)} = 1.75 V @ I_C = 30 A
- High Input Impedance
- RoHS Compliant

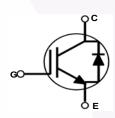
Applications

• Induction Heating, Microwave Oven

General Description

Using advanced field stop trench and shorted-anode technology, Fairchild's shorted-anode Trench IGBTs offer superior conduction and switching performances for soft switching applications. The device can operate in parallel configuration with exceptional avalanche capability. This device is designed for induction heating and microwave oven.





Absolute Maximum Ratings T_C = 25°C unless otherwise noted

Symbol	Description		Ratings	Unit	
V _{CES}	Collector to Emitter Voltage		1300	V	
V _{GES}	Gate to Emitter Voltage		±25	V	
I _C	Collector Current	@ $T_{C} = 25^{\circ}C$	60	A	
	Collector Current	@ T _C = 100 ^o C	30	A	
I _{CM (1)}	Pulsed Collector Current		150	A	
l _F	Diode Continuous Forward Current	@ T _C = 25°C	60	A	
I _F	Diode Continuous Forward Current	@ T _C = 100 ^o C	30	А	
P _D	Maximum Power Dissipation	@ T _C = 25°C	348	W	
	Maximum Power Dissipation	@ T _C = 100°C	174	W	
TJ	Operating Junction Temperature		-55 to +175	°C	
T _{stg}	Storage Temperature Range		-55 to +175	°C	
TL	Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 seconds		300	°C	

Thermal Characteristics

Symbol	Parameter	Тур.	Max.	Unit	
$R_{\theta JC}(IGBT)$	Thermal Resistance, Junction to Case		0.43	°C/W	
R_{\thetaJA}	Thermal Resistance, Junction to Ambient		40	°C/W	

Notes:

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1: Limited by Tjmax

April 2016

Part Nu	mber	ber Top Mark	Package	Packing Method	Reel Size	Tape Width		Quantity
FGA30S120P		FGA30S120P	TO-3P	Tube	N/A	N/A	N/A	
				·				
Electric	al Ch	aracteristics	s of the IC	GBT $T_{C} = 25^{\circ}C$ unless otherwise	noted	1		
Symbol	Symbol Parameter			Test Conditions	Min.	Тур.	Max.	Unit
Off Charac	teristics	6						
BV _{CES}	Collector to Emitter Breakdown Voltage			$V_{GE} = 0 V, I_C = 1 mA$	1300	-	-	V
$\Delta {\sf BV}_{\sf CES}$ / $\Delta {\sf T}_{\sf J}$	Temperature Coefficient of Breakdown Voltage			$V_{GE} = 0 V$, $I_C = 1 mA$	-	1.3	-	V/ºC
I _{CES}	Collect	or Cut-Off Current		$V_{CE} = 1300, V_{GE} = 0V$	-	-	1	mA
I _{GES}	G-E Leakage Current			$V_{GE} = V_{GES}, V_{CE} = 0V$	-	-	±500	nA
On Charac	teristics							
V _{GE(th)}	G-E Th	reshold Voltage		$I_{C} = 30 \text{mA}, V_{CE} = V_{GE}$	4.5	6.0	7.5	V
V _{CE(sat)}		Collector to Emitter Saturation Voltage		$I_{C} = 30A, V_{GE} = 15V$ $T_{C} = 25^{\circ}C$	-	1.75	2.3	V
	Collect			$I_{C} = 30A, V_{GE} = 15V,$ $T_{C} = 125^{\circ}C$	-	1.85	-	V
				$I_{C} = 30A, V_{GE} = 15V,$ $T_{C} = 175^{o}C$	-	1.9	-	V
V _{FM}	Diode I	Diode Forward Voltage		$I_F = 30A, T_C = 25^{\circ}C$	-	1.7	2.2	V
				I _F = 30A, T _C = 175 ^o C	-	2.1	-	V
Dynamic C	haracte	ristics	_					
C _{ies}	Input C	apacitance			-	3345	-	pF
C _{oes}	Output	Output Capacitance		V _{CE} = 30V, V _{GE} = 0V, f = 1MHz	-	75	-	pF
C _{res}	Revers	e Transfer Capacita	ance		-	60	-	pF
Switching	Characo	teristics						
t _{d(on)}	Turn-O	Turn-On Delay Time			-	39	-	ns
t _r	Rise Ti	me			-	360	-	ns
t _{d(off)}	Turn-O	ff Delay Time		$V_{CC} = 600V, I_C = 30A,$	-	620	-	ns
t _f	Fall Tin	ne		$R_{G} = 10\Omega, V_{GE} = 15V,$	-	160	-	ns
Eon	Turn-O	n Switching Loss		Resistive Load, $T_C = 25^{\circ}C$	-	1.3	-	mJ
E _{off}	Turn-O	ff Switching Loss			-	1.22	-	mJ
E _{ts}	Total S	witching Loss			-	2.52	-	mJ
t _{d(on)}	Turn-O	n Delay Time			-	38	-	ns
t _r	Rise Ti	me			-	375	-	ns
t _{d(off)}	Turn-O	ff Delay Time		$V_{CC} = 600V, I_C = 30A,$	-	635	-	ns
t _f	Fall Tin	ne		$R_G = 10\Omega$, $V_{GE} = 15V$, Resistive Load, $T_C = 175^{\circ}C$	-	270	-	ns
E _{on}	Turn-O	Turn-On Switching Loss		Nesistive Load, TC = 175°C	-	1.59	-	mJ
E _{off}	Turn-O	ff Switching Loss			-	1.78	-	mJ
E _{ts}	Total S	witching Loss			-	3.37	-	mJ
Qg	Total G	ate Charge			-	78	-	nC
Q _{ge}	Gate to	Emitter Charge		$V_{CE} = 600V, I_C = 30A, V_{GE} = 15V$	-	4.2	-	nC
Q _{gc}	Gate to	Collector Charge		GE - 10 V	-	33.3	-	nC

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Typical Performance Characteristics



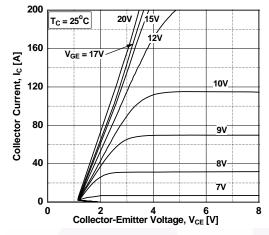


Figure 3. Typical Saturation Voltage Characteritics

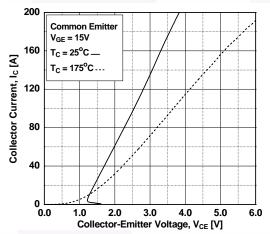


Figure 5. Saturation Voltage vs. Case Temperature at Variant Current Level

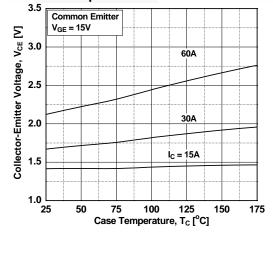


Figure 2. Typical Output Characteristics

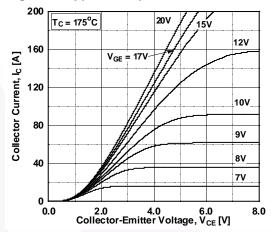


Figure 4. Transfer Characteristics

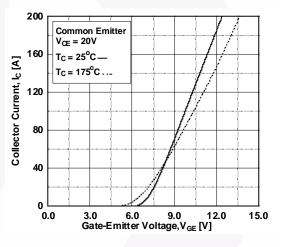
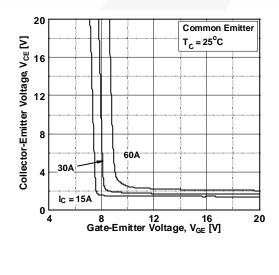


Figure 6. Saturation Voltage vs. VGE



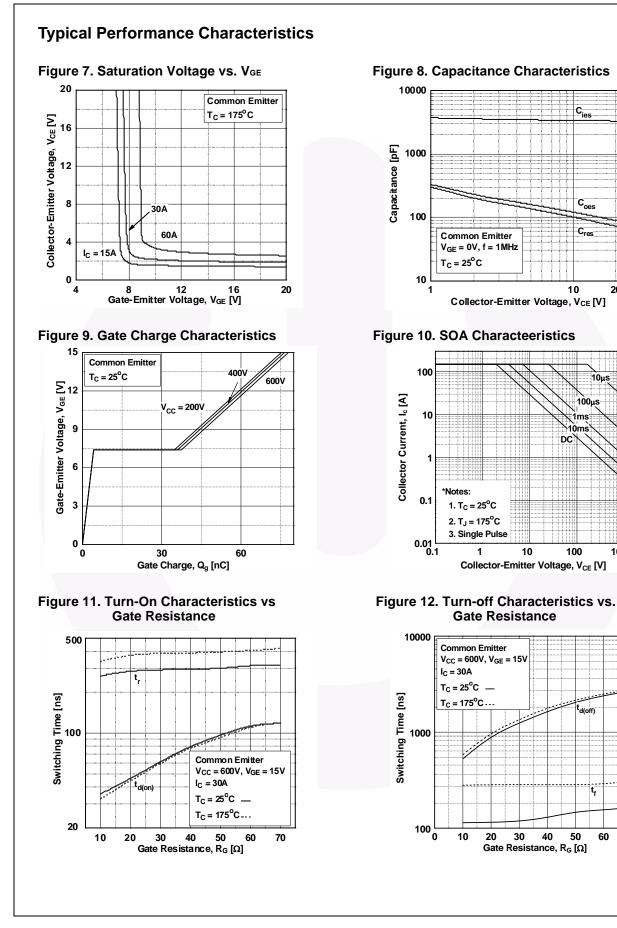
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FGA30S120P — 1300 V, 30 A Shorted-anode IGBT

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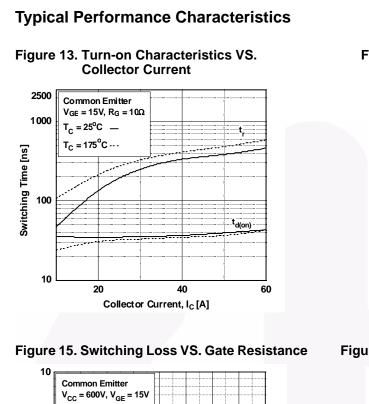
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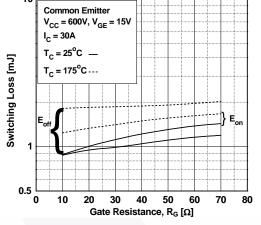
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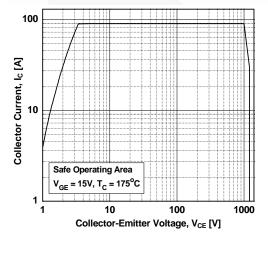
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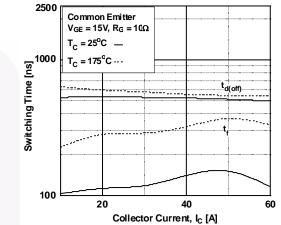


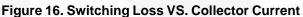


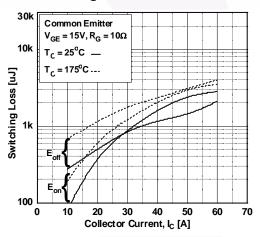


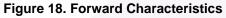


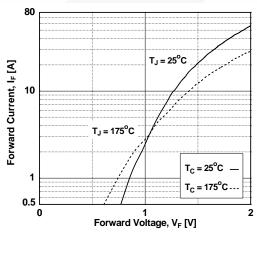


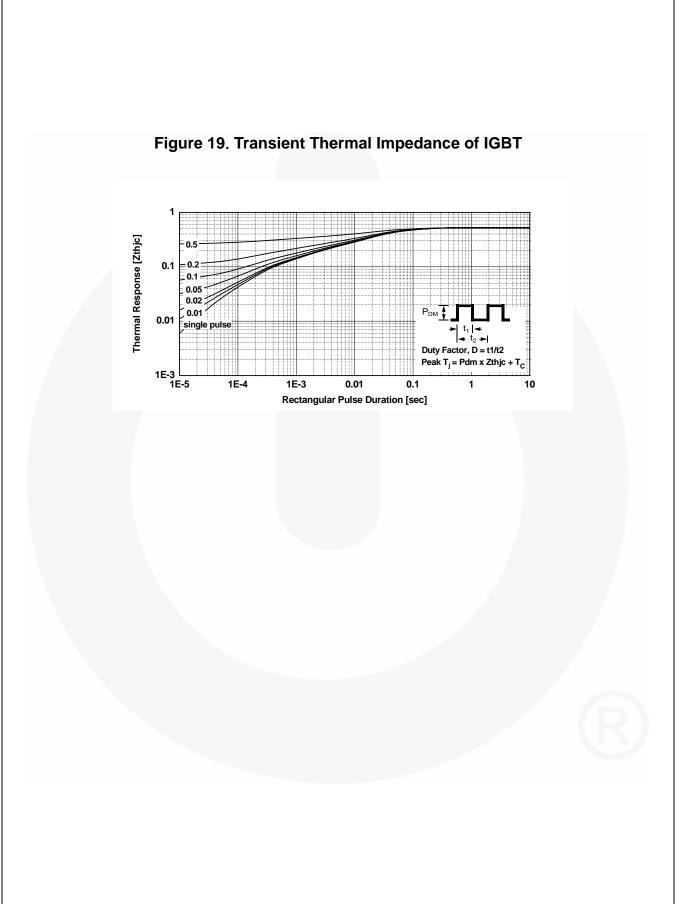


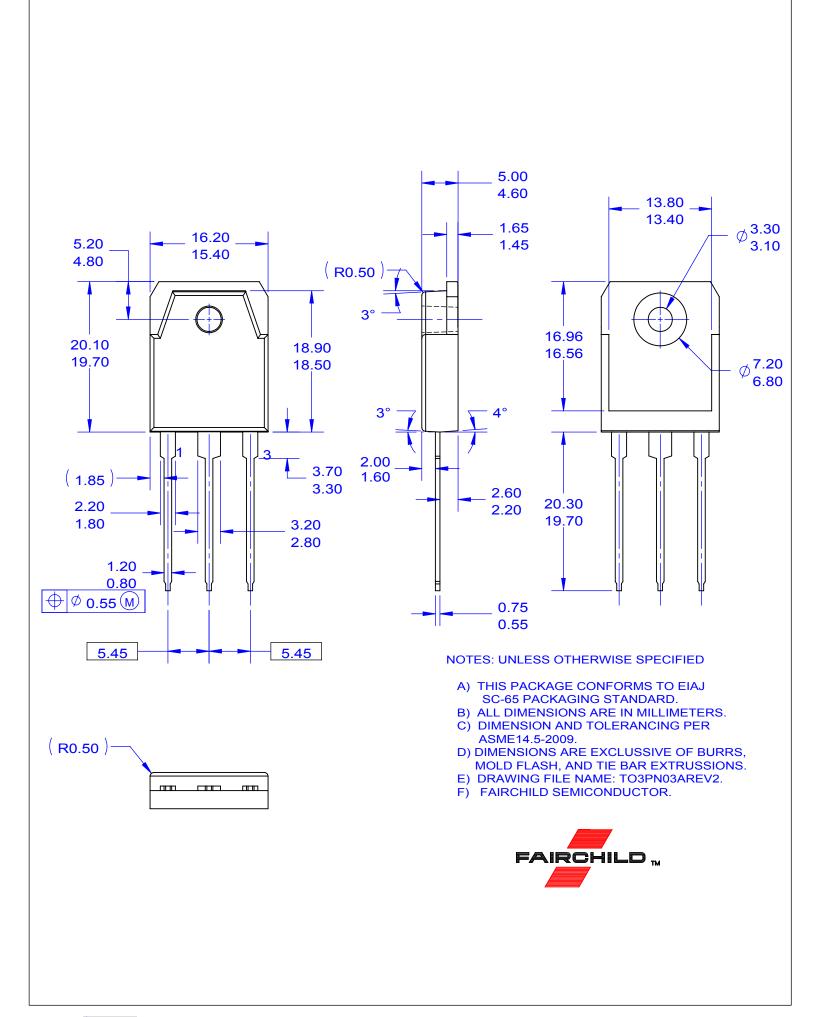












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